

# MCH3481

## Power MOSFET 20V, 104mΩ, 2A, Single N-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

### Features

- Low On-Resistance
- 1.2V drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

### Typical Applications

- Load Switch

### SPECIFICATIONS

**ABSOLUTE MAXIMUM RATING** at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V <sub>DSS</sub>	20	V
Gate to Source Voltage	V <sub>GS</sub>	±9	V
Drain Current (DC)	I <sub>D</sub>	2	A
Drain Current (Pulse) PW ≤ 10μs, duty cycle ≤ 1%	I <sub>DP</sub>	8	A
Power Dissipation When mounted on ceramic substrate (900mm <sup>2</sup> × 0.8mm)	P <sub>D</sub>	0.8	W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm <sup>2</sup> × 0.8mm)	R <sub>θJA</sub>	156.2	°C/W

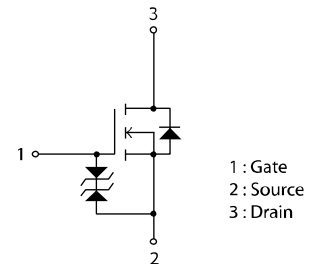


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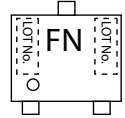
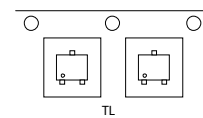
V <sub>DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max
20V	104mΩ@ 4.5V	2A
	147mΩ@ 2.5V	
	203mΩ@ 1.8V	
	540mΩ@ 1.2V	

### ELECTRICAL CONNECTION N-Channel



**PACKING TYPE : TL**

**MARKING**



### ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

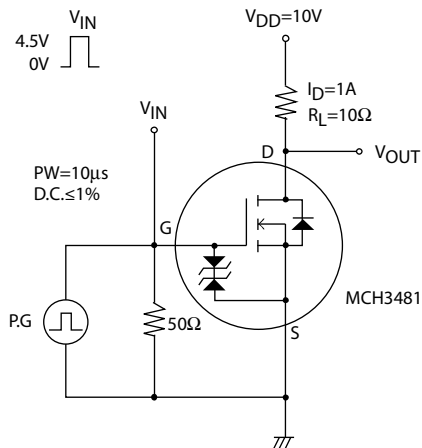
# MCH3481

## ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 2)

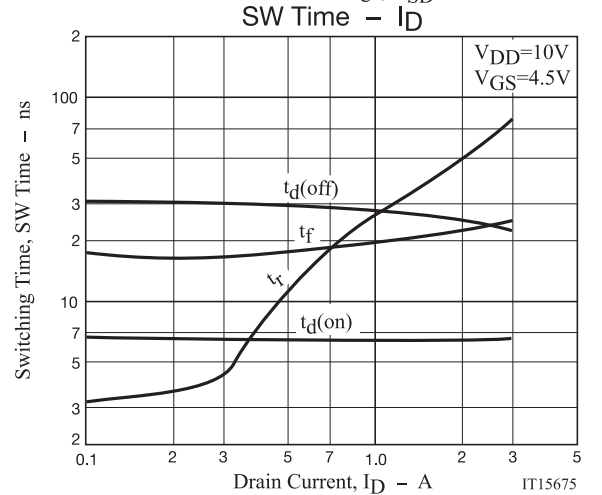
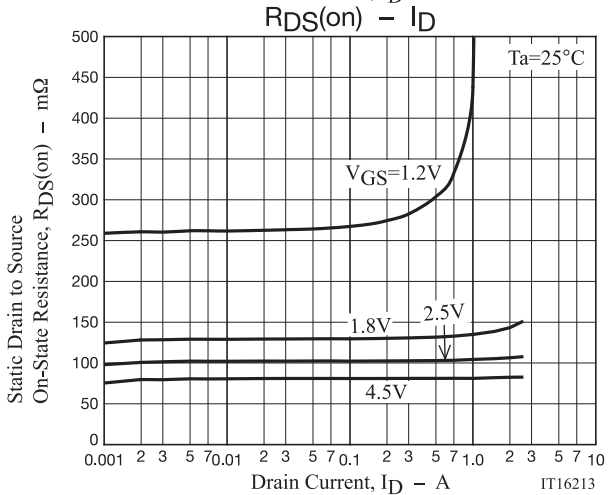
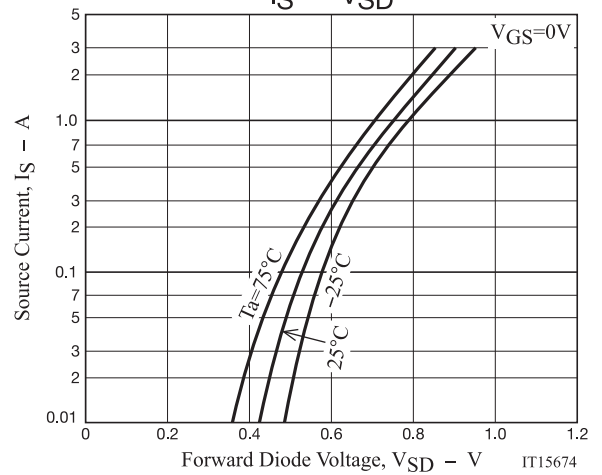
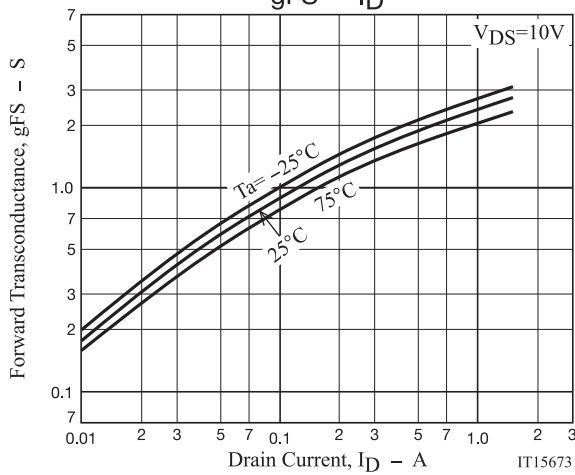
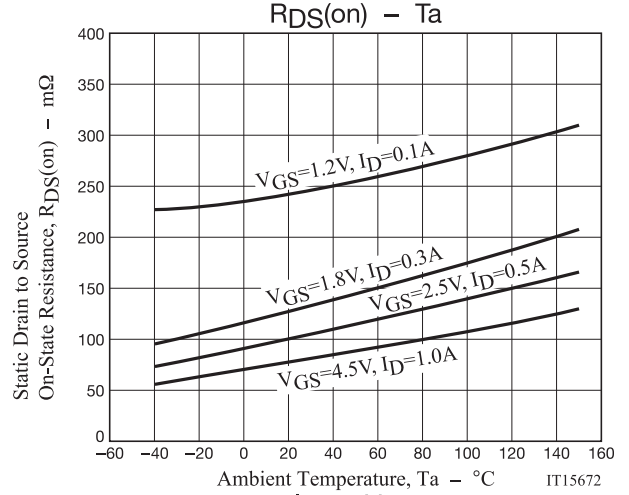
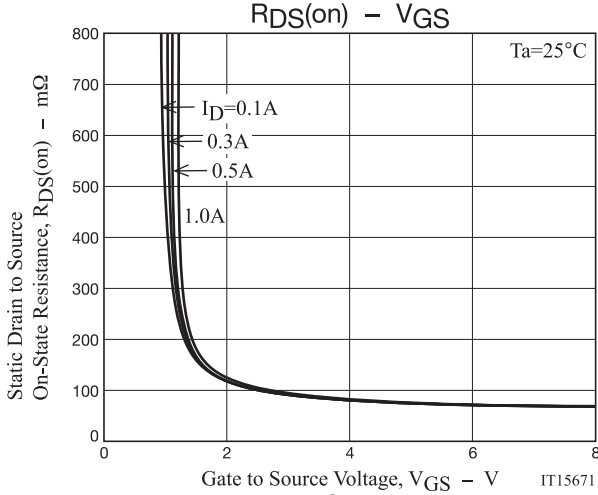
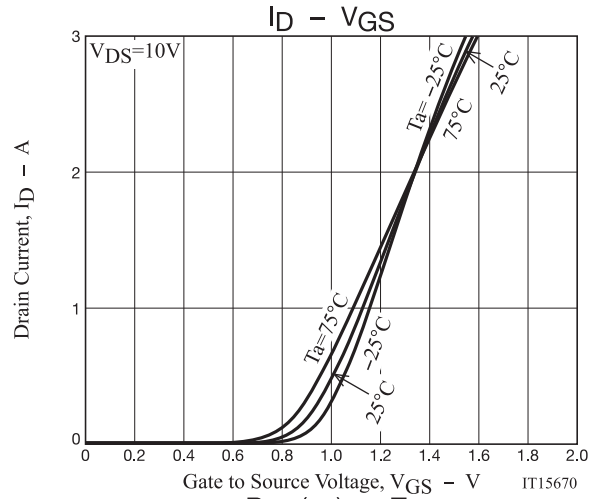
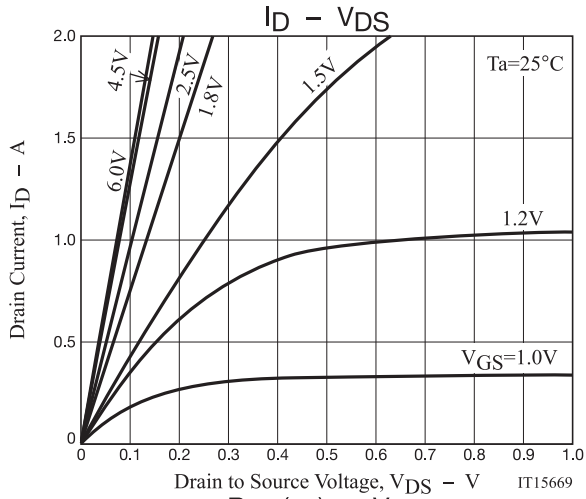
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μA
Gate to Source Leakage Current	IGSS	VGS=±7.2V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=10V, ID=1mA	0.3		0.9	V
Forward Transconductance	gFS	VDS=10V, ID=1A		2.4		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=1A, VGS=4.5V		80	104	mΩ
	RDS(on)2	ID=0.5A, VGS=2.5V		105	147	mΩ
	RDS(on)3	ID=0.3A, VGS=1.8V		135	203	mΩ
	RDS(on)4	ID=0.1A, VGS=1.2V		270	540	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		175		pF
Output Capacitance	Coss			30		pF
Reverse Transfer Capacitance	Crss			25		pF
Turn-ON Delay Time	tj(on)			6.6		ns
Rise Time	tr	See specified Test Circuit		27		ns
Turn-OFF Delay Time	tj(off)			28		ns
Fall Time	tf			19		ns
Total Gate Charge	Qg	VDS=10V, VGS=4.5V, ID=2A		2.9		nC
Gate to Source Charge	Qgs			0.46		nC
Gate to Drain "Miller" Charge	Qgd			0.53		nC
Forward Diode Voltage	VSD	IS=2A, VGS=0V		0.85	1.2	V

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

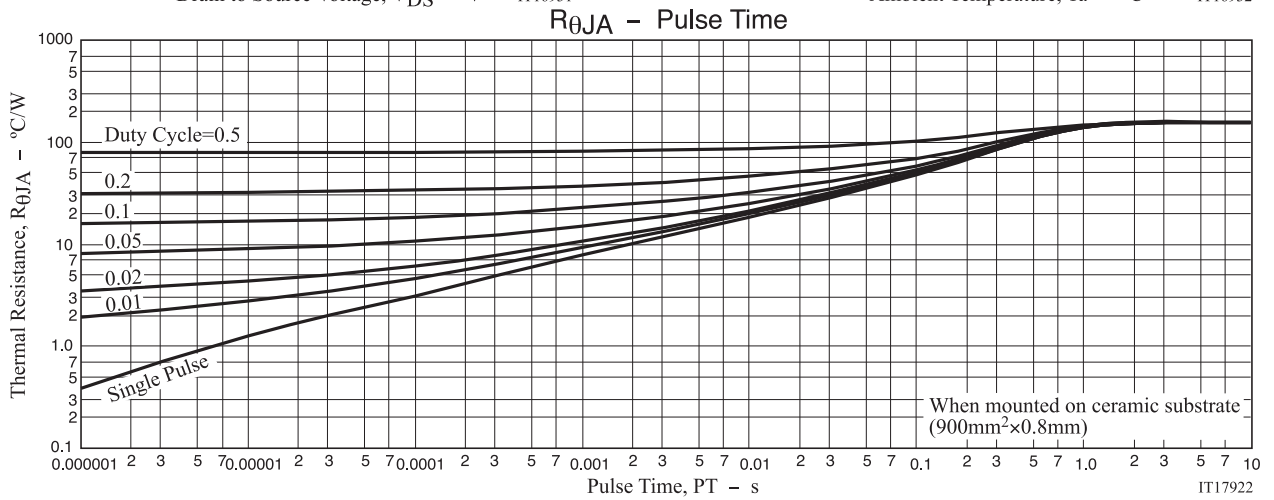
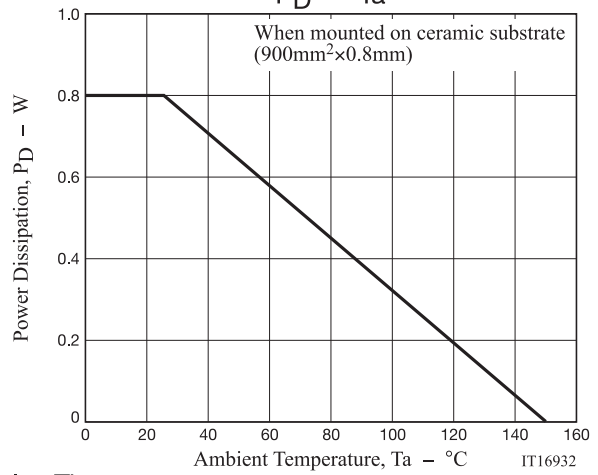
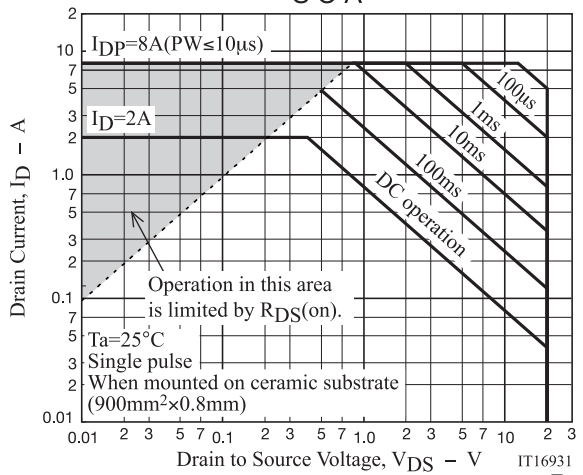
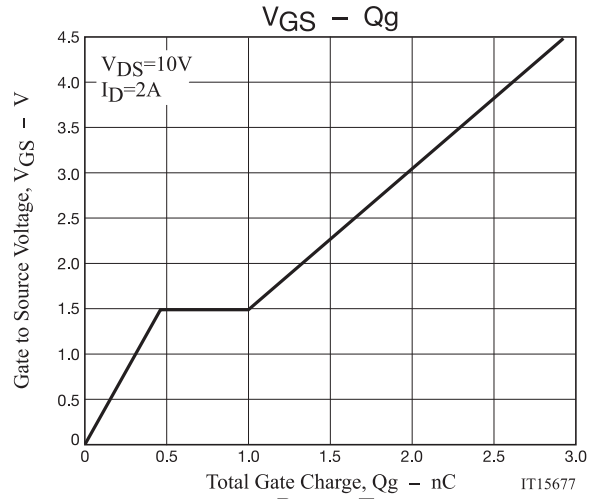
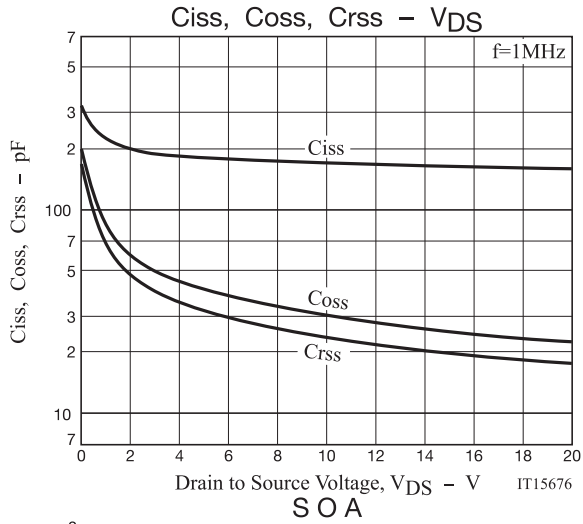
### Switching Time Test Circuit



# MCH3481



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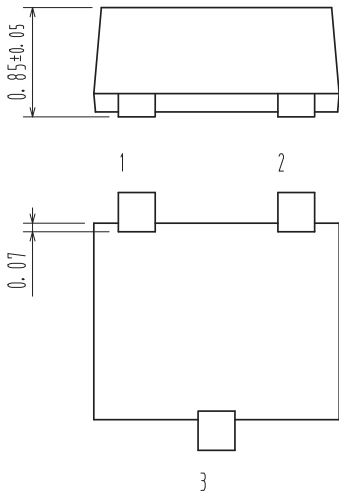
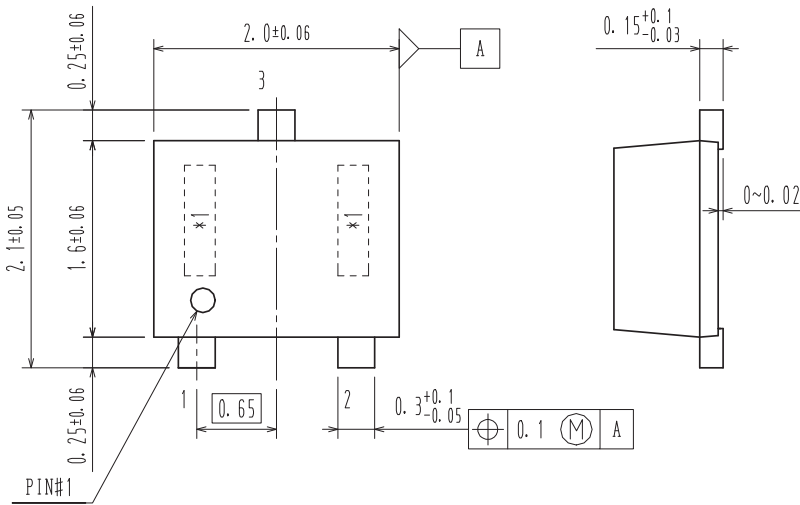


# MCH3481

## PACKAGE DIMENSIONS

unit : mm

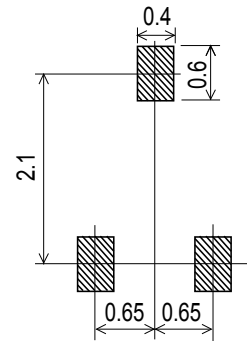
SC-70FL / MCPH3  
CASE 419AQ  
ISSUE O



\*1: Lot indication

- 1 : Gate
- 2 : Source
- 3 : Drain

### Recommended Soldering Footprint



## ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
MCH3481-TL-H	FN	SC-70FL / MCPH3 (Pb-Free / Halogen Free)	3,000 / Tape & Reel
MCH3481-TL-W			

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. [http://www.onsemi.com/pub\\_link/Collateral/BRD8011-D.PDF](http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF)

Note on usage : Since the MCH3481 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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